Volts

**CURRENT:** 

# Specification For Approval

**Ampers** 

**Marking And Polarity** 

3

#### FAST RECOVERY BRIDGE RECTIFIERS

#### **FEATURES**

**VOLTAGE:** 

- Glass Passivated Chip Junction
- Super Fast Recovery Time For High Efficiency

1000

- Low Leakage Current For High Reliability
- High Forward Surge Capability For High Reliability

#### **MECHANICAL DATA**

- Package: Molding Compound Meets UL 94 V-0 Flammability Rating, RoHS-Compliant
- Polarity: As Marked On Case
- Mounting Position: Any
- Weight:App. 0.339 Grams (0.01195 Ounce)

#### **TYPICAL APPLICATIONS**

 General Purpose Use In AC/DC BridgeFull Waverectification For PD,Adapter, Power Supply, Monitor,LED Driver,Printer,Audio Equipment, TV And Homeappliances Etc. Applications.

## 

#### Remark:

Package:

1. NH=Niuhang Trademark

**DBS** 

- ②. FF=Product Line Code,According To Actual Changes YWW=Date Code,According To Actual Changes RB307S=Model
- ③. +=Polarity Mark

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%

Maximum Ratings (Ta=25℃ Unless Otherwise Specified)				
Parameter	Test Conditions	Symbol	RB307S	Unit
Maximum Repetitive Peak Reverse Voltage		$V_{RRM}$	1000	v
Maximum RMS Voltag		V <sub>RMS</sub>	700	V
Maximum DC Blocking Voltage		V <sub>DC</sub>	1000	V
Maximum Average Forward Rectified Current	@TC= 100 °C	I <sub>F(AV)</sub>	3	Α
Peak Forward Surge Current	8.3ms Single Half Sine-wave Superimposed On Rate Load	I <sub>FSM</sub>	85	А
Current Squared Time Per Diode	t<8.3ms	l <sup>2</sup> t	30.0	A <sup>2</sup> sec

#### Electrical Characteristcs (Ta=25℃ Unless Otherwise Specified ) **RB307S** Parameter **Test Conditions** Symbol Unit Min. Тур. Max. Ta=25℃ 1.10 1.25 ν Instaneous Forward Voltage Per Diode (note1) $I_F = 3.0$ A $V_{\text{F}}$ Ta=125℃ 1.00 1.17 Ta=25°C $V_R = V_{RRM}$ 1.00 5.00 Maximum DC Reverse Current At Rated DC uΑ I<sub>RRM</sub> Blocking Voltage (Note 1) Ta=125℃ $V_R = 80\%*V_{RRM}$ 50.00 500 00 Typical Junction Capacitance Per Diode 4.0 V,1MHz 25.00 C, рF Maximum Reverse Recovery Time $I_F$ =0.5A, $I_R$ =1.0A, $I_{RR}$ =0.25A ----500.00 nS T<sub>RR</sub>

Thermal Characteristcs (Ta=25℃ Unless Otherwise Specified )						
Parameter	Symbol		RB307S			Unit
Operating Junction Temperature Range	TJ	-55	to	150		·~
Storage Temperature Range	T <sub>STD</sub>	-55	to	150		C
Typical Thermal Resistance (Note 2)	R <sub>0JA</sub>	68.0		°C/W		
Typical Memal Nesistance (Note 2)	R <sub>eJC</sub>		10.0			CIW

Notes: 1.Pulse Test: 300 Us Pulse Width,1% Duty Cycle

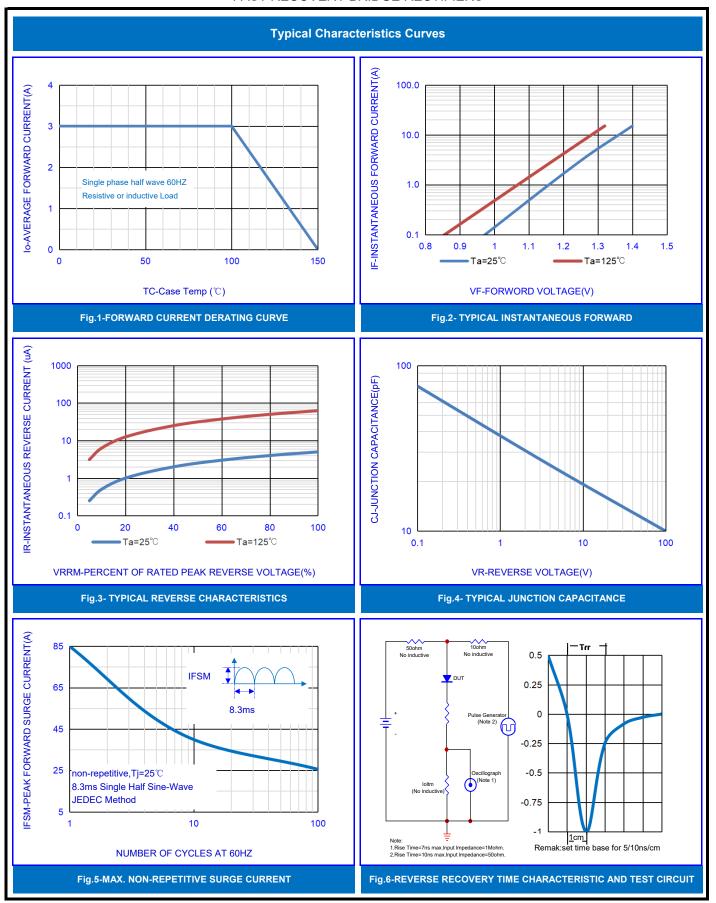
2.Device Mounted On Device Mounted On 75mm x 45mm x 5.5mm Aluminum Plate Heatsink.

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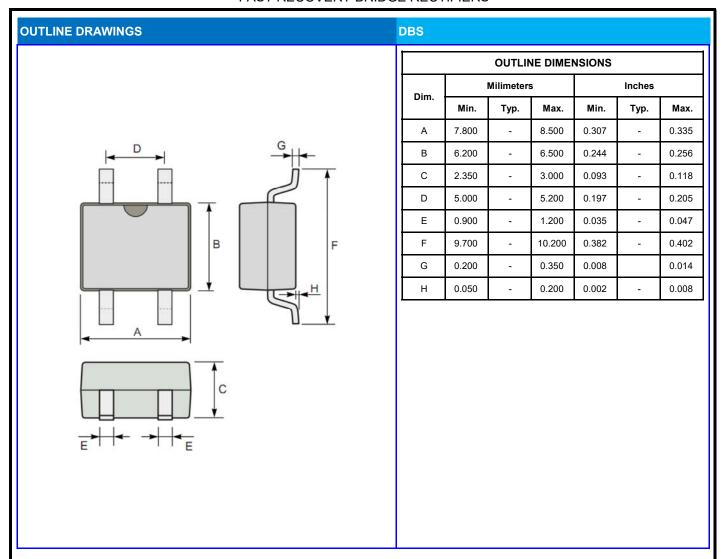
#### FAST RECOVERY BRIDGE RECTIFIERS







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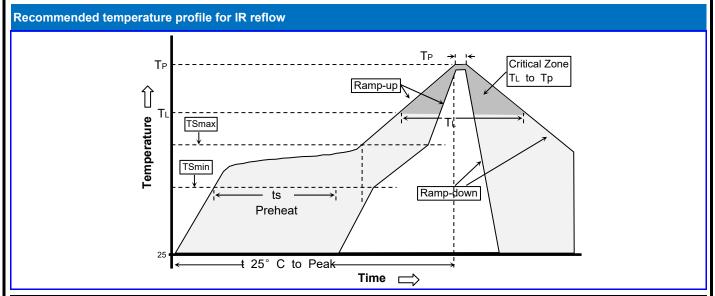


PACKING INFORMATION					
Package Code	Package Method	Inner Box Size L×W×H(mm)	Quantity (Pcs/Inner Box)	Outer Carton Size L×W×H(mm)	Quantity (Pcs/Carton)
DBS	Tape Reel	340X340X40	3000	360×360×380	27000



#### FAST RECOVERY BRIDGE RECTIFIERS

Recommended wave soldering condition					
Product	Peak Temperature	Soldering Time			
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds			



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.
Preheat -Temperature Min(TS min) -Temperature Max(TS max) -Time(ts min to ts max)	100°C 150°C 60-120 seconds	150°C 200°C 60-180 seconds
Time maintained above: -Temperature (TL) - Time (tL)	183°C 60-150 seconds	217°C 60-150 seconds
Peak Temperature(TP)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note: All temperatures refer to topside of the package, measured on the package body surface.



#### FAST RECOVERY BRIDGE RECTIFIERS

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